NSN 5962-01-261-9626

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-261-9626

Body Length:
0.550 inches
Body Width:
0.450 inches
Body Height:
0.120 inches
Maximum Power Dissipation Rating:
275.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
23 input
Case Outline Source And Designator:
C-12 mil-m-38510
Current Rating Per Characteristic:
25.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
14.0 volts total supply
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

NSN 5962-01-261-9626

Memory Microcircuit - Page 2 of 2

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